

74LVC1G240-Q100

Single inverting buffer/line driver; 3-state

Rev. 1 — 1 November 2023

Product data sheet

1. General description

The 74LVC1G240-Q100 is a 1-bit inverting buffer/line driver with 3-state output. The device features an output enable \overline{OE} . A HIGH on \overline{OE} causes the output to assume a high-impedance OFF-state. Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V environments.

Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times.

This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and -40 °C to +125 °C
- Wide supply voltage range from 1.65 V to 5.5 V
- Overvoltage tolerant inputs to 5.5 V
- High noise immunity
- CMOS low power dissipation
- I_{OFF} circuitry provides partial Power-down mode operation
- ± 24 mA output drive ($V_{CC} = 3.0$ V)
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Complies with JEDEC standard:
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8C (2.7 V to 3.6 V)
 - JESD36 (4.5 V to 5.5 V)
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V

3. Ordering information

Table 1. Ordering information

Type number	Package			Version
	Temperature range	Name	Description	
74LVC1G240GW-Q100	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1

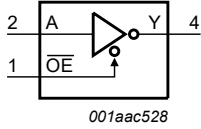
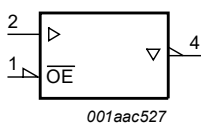
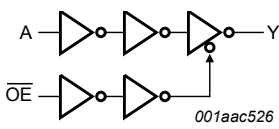
4. Marking

Table 2. Marking codes

Type number	Marking code [1]
74LVC1G240GW-Q100	V2

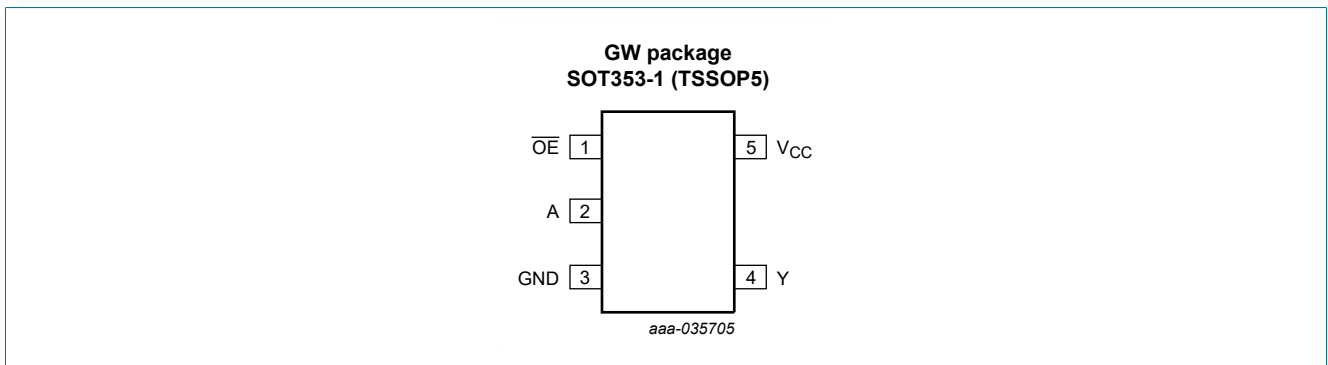
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram

 <p>Fig. 1. Logic symbol</p>	 <p>Fig. 2. IEC logic symbol</p>	 <p>Fig. 3. Logic diagram</p>
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6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
\overline{OE}	1	output enable input
A	2	data input
GND	3	ground (0 V)
Y	4	data output
V_{CC}	5	supply voltage

7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level; X = Don't care; Z = high-impedance OFF-state.

Input		Output
OE	A	Y
L	L	H
L	H	L
H	X	Z

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+6.5	V
I_{IK}	input clamping current	$V_I < 0$ V	-50	-	mA
V_I	input voltage		[1] -0.5	+6.5	V
I_{OK}	output clamping current	$V_O > V_{CC}$ or $V_O < 0$ V	-	±50	mA
V_O	output voltage	Active mode	[1] -0.5	$V_{CC} + 0.5$	V
		Power-down mode; $V_{CC} = 0$ V	[1] -0.5	+6.5	V
I_O	output current	$V_O = 0$ V to V_{CC}	-	±50	mA
I_{CC}	supply current		-	100	mA
I_{GND}	ground current		-100	-	mA
P_{tot}	total power dissipation	$T_{amb} = -40$ °C to +125 °C	[2] -	250	mW
T_{stg}	storage temperature		-65	+150	°C

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT353-1 (TSSOP5) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CC}	supply voltage		1.65	-	5.5	V
V_I	input voltage		0	-	5.5	V
V_O	output voltage	Active mode	0	-	V_{CC}	V
		Power-down mode; $V_{CC} = 0$ V	0	-	5.5	V
T_{amb}	ambient temperature		-40	-	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 1.65$ V to 2.7 V	-	-	20	ns/V
		$V_{CC} = 2.7$ V to 5.5 V	-	-	10	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ [1]	Max	Unit
T_{amb} = -40 °C to +85 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.7	-	-	V
		V _{CC} = 2.7 V to 3.6 V	2.0	-	-	V
		V _{CC} = 4.5 V to 5.5 V	0.7 × V _{CC}	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 1.65 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.8	V
		V _{CC} = 4.5 V to 5.5 V	-	-	0.3 × V _{CC}	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		V _{CC} = 1.65 V to 5.5 V; I _O = 100 μA	-	-	0.1	V
		V _{CC} = 1.65 V; I _O = 4 mA	-	-	0.45	V
		V _{CC} = 2.3 V; I _O = 8 mA	-	-	0.3	V
		V _{CC} = 2.7 V; I _O = 12 mA	-	-	0.4	V
		V _{CC} = 3.0 V; I _O = 24 mA	-	-	0.55	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		V _{CC} = 1.65 V to 5.5 V; I _O = -100 μA	V _{CC} - 0.1	-	-	V
		V _{CC} = 1.65 V; I _O = -4 mA	1.2	-	-	V
		V _{CC} = 2.3 V; I _O = -8 mA	1.9	-	-	V
		V _{CC} = 2.7 V; I _O = -12 mA	2.2	-	-	V
		V _{CC} = 3.0 V; I _O = -24 mA	2.3	-	-	V
I _I	input leakage current	V _{CC} = 0 V to 5.5 V; V _I = 5.5 V or GND	-	±0.1	±1	μA
		V _{CC} = 3.6 V; V _I = V _{IH} or V _{IL} ; V _O = 5.5 V or GND	-	±0.1	±2	μA
		V _{CC} = 0 V; V _I or V _O = 5.5 V	-	±0.1	±2	μA
		V _I = 5.5 V or GND; V _{CC} = 1.65 V to 5.5 V; I _O = 0 A	-	0.1	4	μA
		per pin; V _{CC} = 2.3 V to 5.5 V; V _I = V _{CC} - 0.6 V; I _O = 0 A	-	5	500	μA
			-	5	-	pF
I _{CC}	supply current	V _I = 5.5 V or GND; V _{CC} = 1.65 V to 5.5 V; I _O = 0 A	-	0.1	4	μA
ΔI _{CC}	additional supply current	per pin; V _{CC} = 2.3 V to 5.5 V; V _I = V _{CC} - 0.6 V; I _O = 0 A	-	5	500	μA
C _I	input capacitance		-	5	-	pF

Symbol	Parameter	Conditions	Min	Typ [1]	Max	Unit
T_{amb} = -40 °C to +125 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.7	-	-	V
		V _{CC} = 2.7 V to 3.6 V	2.0	-	-	V
		V _{CC} = 4.5 V to 5.5 V	0.7 × V _{CC}	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 1.65 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.8	V
		V _{CC} = 4.5 V to 5.5 V	-	-	0.3 × V _{CC}	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		V _{CC} = 1.65 V to 5.5 V; I _O = 100 μA	-	-	0.1	V
		V _{CC} = 1.65 V; I _O = 4 mA	-	-	0.70	V
		V _{CC} = 2.3 V; I _O = 8 mA	-	-	0.45	V
		V _{CC} = 2.7 V; I _O = 12 mA	-	-	0.60	V
		V _{CC} = 3.0 V; I _O = 24 mA	-	-	0.80	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		V _{CC} = 1.65 V to 5.5 V; I _O = -100 μA	V _{CC} - 0.1	-	-	V
		V _{CC} = 1.65 V; I _O = -4 mA	0.95	-	-	V
		V _{CC} = 2.3 V; I _O = -8 mA	1.7	-	-	V
		V _{CC} = 2.7 V; I _O = -12 mA	1.9	-	-	V
		V _{CC} = 3.0 V; I _O = -24 mA	2.0	-	-	V
I _I	input leakage current	V _{CC} = 0 V to 5.5 V; V _I = 5.5 V or GND	-	-	±1	μA
		V _{CC} = 4.5 V; I _O = -32 mA	3.4	-	-	V
I _{OZ}	OFF-state output current	V _{CC} = 3.6 V; V _I = V _{IH} or V _{IL} ; V _O = 5.5 V or GND	-	-	±2	μA
I _{OFF}	power-off leakage current	V _{CC} = 0 V; V _I or V _O = 5.5 V	-	-	±2	μA
I _{CC}	supply current	V _I = 5.5 V or GND; V _{CC} = 1.65 V to 5.5 V; I _O = 0 A	-	-	4	μA
ΔI _{CC}	additional supply current	per pin; V _{CC} = 2.3 V to 5.5 V; V _I = V _{CC} - 0.6 V; I _O = 0 A	-	-	500	μA

[1] All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see Fig. 6.

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
t _{pd}	propagation delay	A to Y; see Fig. 4 [2]						
		V _{CC} = 1.65 V to 1.95 V; C _L = 15 pF; R _L = 1 MΩ	1.0	3.8	6.9	1.0	8.7	ns
		V _{CC} = 2.3 V to 2.7 V; C _L = 15 pF; R _L = 1 MΩ	0.5	2.4	4.6	0.5	5.8	ns
		V _{CC} = 3.0 V to 3.6 V; C _L = 15 pF; R _L = 1 MΩ	0.5	1.9	3.7	0.5	4.6	ns
		V _{CC} = 4.5 V to 5.5 V; C _L = 15 pF; R _L = 1 MΩ	0.5	1.6	3.4	0.5	4.2	ns
		A to Y; see Fig. 4 [2]						
		V _{CC} = 1.65 V to 1.95 V; C _L = 30 pF; R _L = 1 kΩ	1.0	3.3	8.0	1.0	10.5	ns
		V _{CC} = 2.3 V to 2.7 V; C _L = 30 pF; R _L = 500 Ω	0.5	2.2	5.5	0.5	7	ns
		V _{CC} = 2.7 V; C _L = 50 pF; R _L = 500 Ω	0.5	2.5	5.5	0.5	7	ns
		V _{CC} = 3.0 V to 3.6 V; C _L = 50 pF; R _L = 500 Ω	0.5	2.1	4.5	0.5	6	ns
V _{CC} = 4.5 V to 5.5 V; C _L = 50 pF; R _L = 500 Ω	0.5	1.7	4.0	0.5	5.5	ns		
t _{en}	enable time	\overline{OE} to Y; see Fig. 5 [3]						
		V _{CC} = 1.65 V to 1.95 V; C _L = 30 pF; R _L = 1 kΩ	1.0	4.1	9.4	1.0	12	ns
		V _{CC} = 2.3 V to 2.7 V; C _L = 30 pF; R _L = 500 Ω	0.5	2.8	6.6	0.5	8.5	ns
		V _{CC} = 2.7 V; C _L = 50 pF; R _L = 500 Ω	0.5	3.3	6.6	0.5	8.5	ns
		V _{CC} = 3.0 V to 3.6 V; C _L = 50 pF; R _L = 500 Ω	0.5	2.4	5.3	0.5	7	ns
		V _{CC} = 4.5 V to 5.5 V; C _L = 50 pF; R _L = 500 Ω	0.5	2.1	5.0	0.5	6.5	ns
t _{dis}	disable time	\overline{OE} to Y; see Fig. 5 [4]						
		V _{CC} = 1.65 V to 1.95 V; C _L = 30 pF; R _L = 1 kΩ	1.0	4.3	9.2	1.0	12	ns
		V _{CC} = 2.3 V to 2.7 V; C _L = 30 pF; R _L = 500 Ω	0.5	2.7	5.0	0.5	6.5	ns
		V _{CC} = 2.7 V; C _L = 50 pF; R _L = 500 Ω	0.5	3.0	5.0	0.5	6.5	ns
		V _{CC} = 3.0 V to 3.6 V; C _L = 50 pF; R _L = 500 Ω	0.5	3.1	5.0	0.5	6.5	ns
		V _{CC} = 4.5 V to 5.5 V; C _L = 50 pF; R _L = 500 Ω	0.5	2.2	4.2	0.5	5.5	ns
C _{PD}	power dissipation capacitance	V _I = GND to V _{CC} ; f _i = 10 MHz [5]						
		output enabled	-	25	-	-	-	pF
		output disabled	-	6	-	-	-	pF

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.8 V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively.

[2] t_{pd} is the same as t_{PLH} and t_{PHL}

[3] t_{en} is the same as t_{PZH} and t_{PZL}

[4] t_{dis} is the same as t_{PLZ} and t_{PHZ}

[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

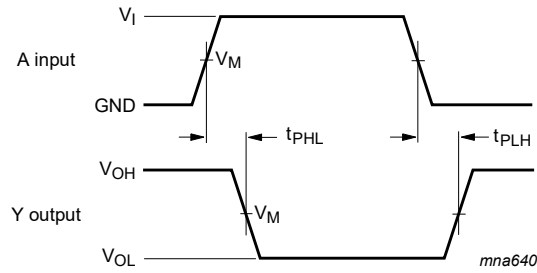
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

$\sum(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

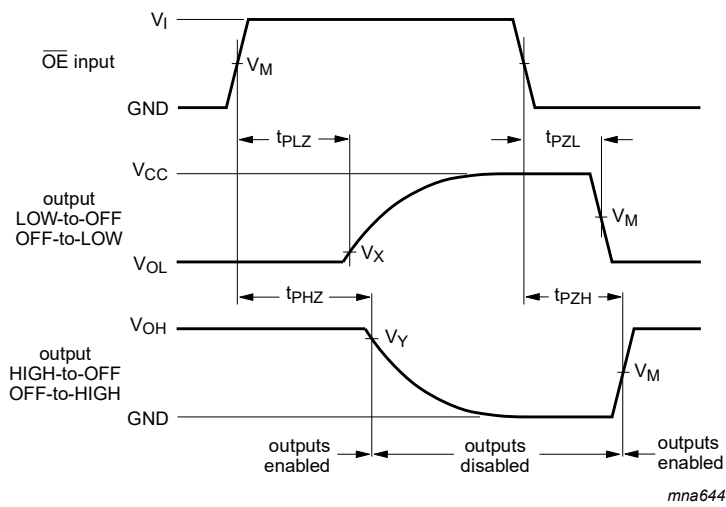
11.1. Waveforms and test circuit



Measurement points are given in [Table 9](#).

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 4. The data input (A) to output (Y) propagation delays



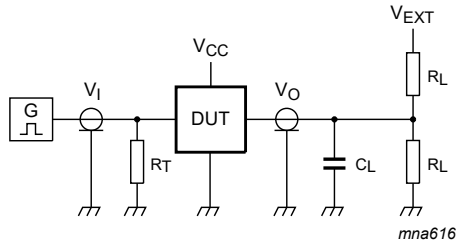
Measurement points are given in [Table 9](#).

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 5. 3-state enable and disable times

Table 9. Measurement points

Supply voltage	Input	Output		
V_{CC}	V_M	V_M	V_X	V_Y
1.65 V to 1.95 V	$0.5V_{CC}$	$0.5V_{CC}$	$V_{OL} + 0.15 V$	$V_{OH} - 0.15 V$
2.3 V to 2.7 V	$0.5V_{CC}$	$0.5V_{CC}$	$V_{OL} + 0.15 V$	$V_{OH} - 0.15 V$
2.7 V	1.5 V	1.5 V	$V_{OL} + 0.3 V$	$V_{OH} - 0.3 V$
3.0 V to 3.6 V	1.5 V	1.5 V	$V_{OL} + 0.3 V$	$V_{OH} - 0.3 V$
4.5 V to 5.5 V	$0.5V_{CC}$	$0.5V_{CC}$	$V_{OL} + 0.3 V$	$V_{OH} - 0.3 V$



Test data is given in [Table 10](#).

Definitions for test circuit:

R_L = Load resistance;

C_L = Load capacitance including jig and probe capacitance;

R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator;

V_{EXT} = External voltage for measuring switching times.

Fig. 6. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Input		V_{EXT}		
V_{CC}	V_I	t_r, t_f	t_{PLH}, t_{PHL}	t_{PZH}, t_{PHZ}	t_{PZL}, t_{PLZ}
1.65 V to 1.95 V	V_{CC}	≤ 2.0 ns	open	GND	$2V_{CC}$
2.3 V to 2.7 V	V_{CC}	≤ 2.0 ns	open	GND	$2V_{CC}$
2.7 V	2.7 V	≤ 2.5 ns	open	GND	6 V
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	open	GND	6 V
4.5 V to 5.5 V	V_{CC}	≤ 2.5 ns	open	GND	$2V_{CC}$

12. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1

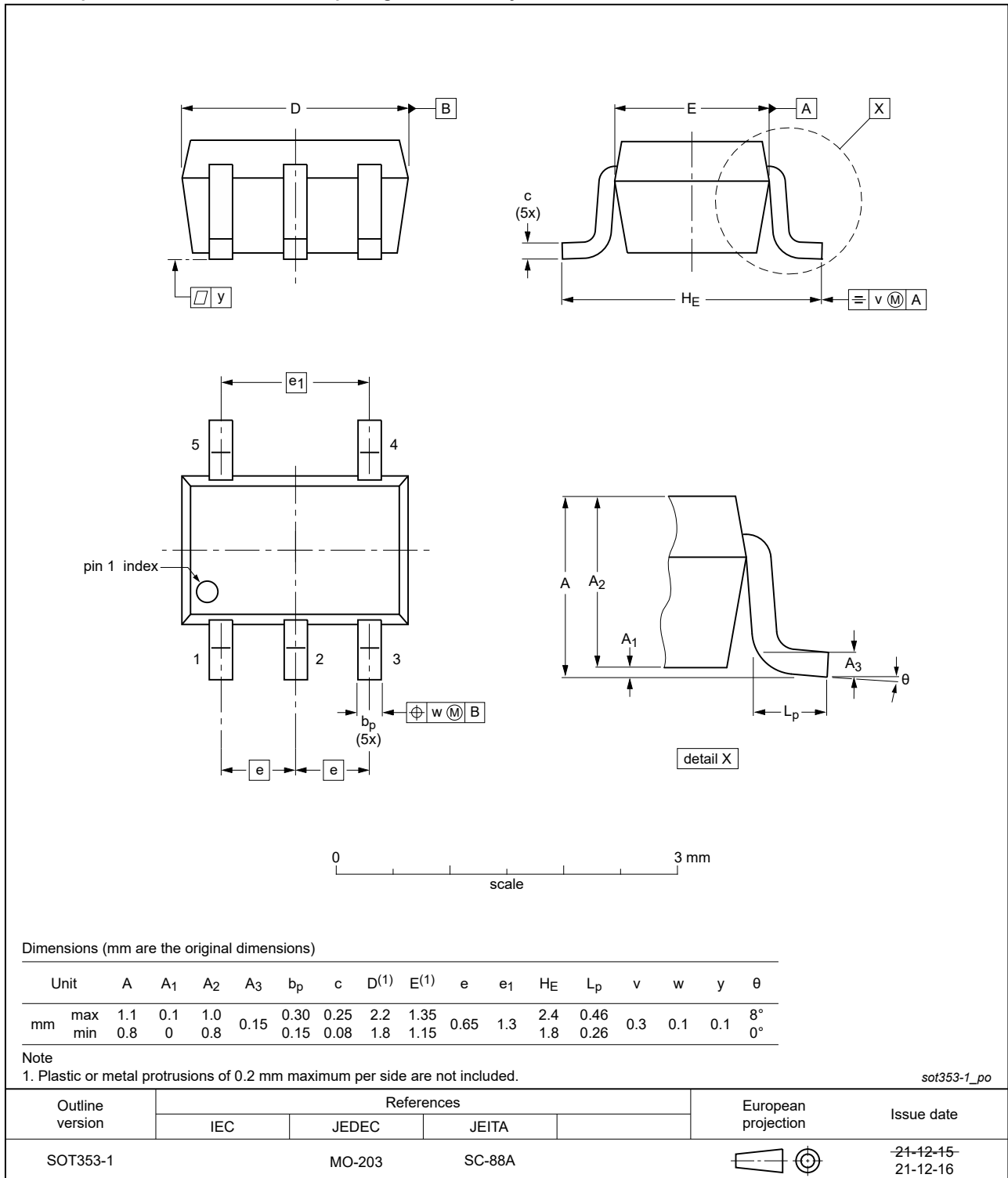


Fig. 7. Package outline SOT353-1 (TSSOP5)

13. Abbreviations

Table 11. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC1G240_Q100 v.1	20231101	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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